

## SPDT RF Switch

### M3SW-2-50DRA+

50Ω DC to 4500 MHz Reflective RF Switch with Internal Driver

#### **THE BIG DEAL**

- · High Isolation, 48 dB typ.
- High Input IP3, +47.3 dBm typ.
- Low Insertion loss, 0.6 dB typ.
- Fast Rise/Fall time, 3.3 ns / 4.6 ns typ.
- Tiny Size, 3.25 x 3.25 x 0.9 mm



Generic photo used for illustration purposes only CASE STYLE: DL805

+RoHS Compliant
The +Suffix identifies RoHS Compliance.
See our website for methodologies and qualifications

#### **APPLICATIONS**

- Defense
- Communication Infrastructure
- Test and Measurement

#### **PRODUCT OVERVIEW**

M3SW-2-50DRA+ is a high isolation fast switching reflective GaAs PHEMT SPDT switch with an internal driver. It operates at +5V & -5V power supplies and has a single TLL compatible control port. It has been designed for wideband operation and packaged in a tiny 3.25mm x 3.25mm, 8-lead package.

#### **KEY FEATURES**

Features	Advantages
Wideband, DC to 4.5 GHz	One model can be used in many applications, saving component count. Also ideal for wideband applications such as military and instrumentation.
High Isolation: 52 dB at 1000 MHz 36 dB at 4500 MHz	High isolation significantly reduces leakage of power into OFF ports.
High linearity: Input power at P1dB, 25 dBm typ. Input IP3, +47.3 dBm typ.	High linearity minimizes unwanted inter modulation products which are difficult or impossible to filter in multi- carrier environments such as CATV, or in the presence of strong interfering signal from adjacent circuitry or received by antenna.
Form-fit compatible with M3SW-2-50DR+	Fits into existing PCB footprint designed for M3SW-2-50DR+ with minor electrical differences.
Tiny size, 3.25 x 3.25 mm MCLP package	Tiny footprint saves space in dense layouts while providing low inductance, repeatable transitions, and excellent thermal contact to the PCB.

REV. A ECO-014399 M3SW-2-50DRA+ GY/RS/CP 220729





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### RF ELECTRICAL SPECIFICATIONS¹, $T_{AMB}$ =25°C, 50 $\Omega$ , $V_{DD}$ = +5V, $V_{EE}$ = -5V

Parameter	Condition (MHz)	Min.	Тур.	Max.	Units
Frequency Range <sup>3</sup>		DC		4500	MHz
	10-100		0.5	1.0	
	100-1000		0.5	1.2	
Insertion Loss	1000-2000		0.6	1.4	dB
	2000-4000		0.7	2.1	
	4000-4500		1.4	2.5	
	10-100		78		
	100-1000		59		
Isolation between Output Port 1 & 2	1000-2000		48		dB
	2000-4000		40		
	4000-4500		34		
	10-100	70	79		
	100-1000	49	59		
Isolation between Common Port & Output Ports	1000-2000	41	48		dB
	2000-4000	30	39		
	4000-4500	30	35		
	10-100		30		
	100-1000		30		
Input Return Loss	1000-2000		25		dB
	2000-4000		21		
	4000-4500		21		
	10-100		29		
0.1.10.1	100-1000		27		
Output Return Loss (ON STATE)	1000-2000		21		dB
(	2000-4000		18		
	4000-4500		13		
	10-100		3		
Outrout Deturn Land	100-1000		3		
Output Return Loss (OFF STATE)	1000-2000		3		dB
,	2000-4000		3		
	4000-4500		3		
	10-100		18.8		
	100-1000		24.1		
Input Power at P1dB <sup>2</sup>	1000-2000		25		dBm
	2000-4000		24.8		
	4000-4500		23.6		
	10-100		38.5		
	100-1000		45.3		
Input IP3 (Pout =0dBm/Tone)	1000-2000		47.3		dBm
	2000-4000		44.9		
	4000-4500		40.2		
Thermal Resistance (Junction-To-Ground Lead at 85°C Stage Temperature)			34.2		degC/W

# SPDT RF Switch M3SW-2-50DRA+

DC to 4500 MHz Reflective RF Switch with Internal Driver 50Ω

#### **DC ELECTRICAL SPECIFICATIONS**

Parameter	Min.	Тур.	Max.	Units
Positive Supply Voltage, V <sub>DD</sub>	4.75	5	5.25	V
Negative Supply voltage, V <sub>EE</sub>	-5.25	-5	-4.75	V
Positive Supply Current, I <sub>DD</sub>	_	5	9	mA
Negative Supply Current, I <sub>EE</sub>	-9	-3	_	mA
Control Voltage Low	_	0	0.8	V
Control Voltage High	2.1	2.3	5	V
Control Current Low	_	0	0.2	mA
Control Current High	_	0.4	5	mA

<sup>1.</sup> Tested on Mini-Circuits' test board TB-M3SW-250DRA+ (See Fig.1)

#### **SWITCHING SPECIFICATIONS**

Parameter	Condition	Min.	Тур.	Max.	Units
ON Time, 50% control to 90% RF			14.4		ns
OFF Time, 50% control to 10% RF	RF Pin= 0 dBm		11.3		ns
Video Leakage	RF Freq.= 500 MHz		42.5		mV
Rise Time, 10% RF to 90% RF 10 to 90% or 90 to 10%	Control Freq.= 500 KHz Control High= 2.3V Control Low= 0V		3.3		ns
Fall Time, 90% RF to 10% RF			4.6		ns

### **MAXIMUM RATINGS<sup>4</sup>**

Parameter	Ratings
Operating temperature	-55°C to +100°C
Storage temperature	-55°C to +100°C
RF Input power	+24 dBm
Junction Temperature	134°C
Total Power Dissipation	0.4W
DC Voltage, Pin 5	+6V
DC Voltage, Pin 7	-6V

<sup>4.</sup> Permanent damage may occur if any of these limits are exceeded. Electrical Maximum ratings are not intended for continuous normal operation.

#### **TRUTH TABLE**

State of Control Voltage	RF-IN to RF-OUT1	RF-IN to RF-OUT 2
LOW	ON	OFF
HIGH	OFF	ON

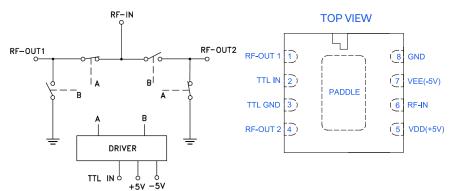
<sup>2.</sup> Input Power at P1dB compression drops to 13 dB at 10 MHz. 3. All RF-ports must be DC blocked or held at 0V DC

## SPDT RF Switch

## M3SW-2-50DRA+

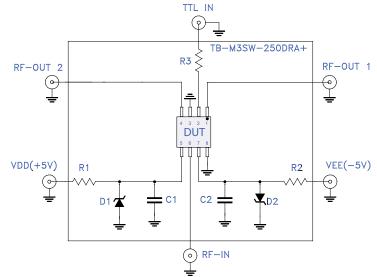
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#### SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION



Function	Pad Number	Description
RF-IN	6	RF Common/ SUM port
RF-OUT1	1	RF Output port #1
RF-OUT2	4	RF Output port #2
TTL IN	2	TTL Compatible Control Voltage Input
TTL GND	3	TTL Ground
V <sub>DD</sub> (+5V)	5	Positive Supply Voltage V <sub>DD</sub>
V <sub>EE</sub> (-5V)	7	Negative Supply Voltage V <sub>EE</sub>
GND	8, paddle	Ground

#### **CHARACTERIZATION & APPLICATION CIRCUIT**



Component	Size	Value	P/N	Manufacturer
DUT	3.25x3.25	N/A	M3SW-2-50DRA+	MCL
D1, D2	SOD-123	Vz = 5.6V	MMSZ4690T1G	ON Semiconductor
R1, R2	0603	11.5Ω	RK73H1JTTD11R5F	KOA
R3	0603	100Ω	RK73H1JTTD1000F	KOA
C1, C2	0603	10pF	06031A100GAT2A	AVX

Note: D1&D2 are optional.

Figure 1. Characterization & Application Circuit

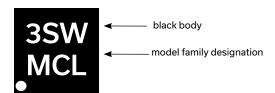
Note: (DUT soldered on Mini-Circuits Characterization & Application Test Board TB-M3SW-2-50DRA+).

Insertion Loss, Amplitude Unbalance, Isolation, Return Loss, Input Power at 1dB Compression (P1dB) & Input IP3 tested using E5071C microwave network analyzer.

#### Condition:

- 1. Insertion Loss, Amplitude Unbalance, Isolation & Return Loss: Pin = 0dBm
- 2. Input IP3(IIP3):Two tones, spaced 1 MHz apart, 0dBm/tone output.

#### **PRODUCT MARKING**



Marking may contain other features or characters for internal lot control

# SPDT RF Switch M3SW-2-50DRA+

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#### ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS

**CLICK HERE** 

Performance Data	Data Table
Performance Data	Swept Graphs
Case Style	DL805 Plastic package, exposed paddle , lead finish=Matte-Tin
Tape & Reel	F58
Standard quantities available on reel	7" reels with 1000 devices 13" reels with 2000, 4000 devices
Suggested Layout for PCB Design	PL-120
Evaluation Board	TB-M3SW-2-50DRA+
Environmental Ratings	ENV16

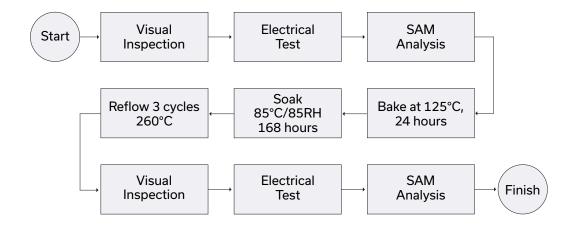
#### **ESD RATING**

Human Body Model (HBM): Class 0 (Pass 100V) in accordance with ESD STM5.1-2001

#### **MSL RATING**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

#### **MSL TEST FLOW CHART**



#### NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini Circuits' website at www.minicircuits.com/terms/viewterm.html